



# PMV160UP

20 V, 1.2 A P-channel Trench MOSFET

Rev. 2 — 6 December 2011

Product data sheet

## 1. Product profile

### 1.1 General description

P-channel enhancement mode Field-Effect Transistor (FET) in a SOT23 (TO-236AB) small Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 1.2 Features and benefits

- 1.8 V  $R_{DSon}$  rated
- Trench MOSFET technology
- Very fast switching

### 1.3 Applications

- Relay driver
- High-side loadswitch
- High-speed line driver
- Switching circuits

### 1.4 Quick reference data

Table 1. Quick reference data

| Symbol                        | Parameter                        | Conditions                                                        | Min                 | Typ | Max  | Unit |
|-------------------------------|----------------------------------|-------------------------------------------------------------------|---------------------|-----|------|------|
| $V_{DS}$                      | drain-source voltage             | $T_j = 25\text{ °C}$                                              | -                   | -   | -20  | V    |
| $V_{GS}$                      | gate-source voltage              |                                                                   | -8                  | -   | 8    | V    |
| $I_D$                         | drain current                    | $V_{GS} = -4.5\text{ V}; T_{amb} = 25\text{ °C}$                  | <a href="#">[1]</a> | -   | -1.2 | A    |
| <b>Static characteristics</b> |                                  |                                                                   |                     |     |      |      |
| $R_{DSon}$                    | drain-source on-state resistance | $V_{GS} = -4.5\text{ V}; I_D = -1.2\text{ A}; T_j = 25\text{ °C}$ | -                   | 170 | 210  | mΩ   |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

## 2. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline      | Graphic symbol   |
|-----|--------|-------------|-------------------------|------------------|
| 1   | G      | gate        | <p>SOT23 (TO-236AB)</p> | <p>017aaa257</p> |
| 2   | S      | source      |                         |                  |
| 3   | D      | drain       |                         |                  |

### 3. Ordering information

Table 3. Ordering information

| Type number | Package  |                                          | Version |
|-------------|----------|------------------------------------------|---------|
|             | Name     | Description                              |         |
| PMV160UP    | TO-236AB | plastic surface-mounted package; 3 leads | SOT23   |

### 4. Marking

Table 4. Marking codes

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| PMV160UP    | NH%                         |

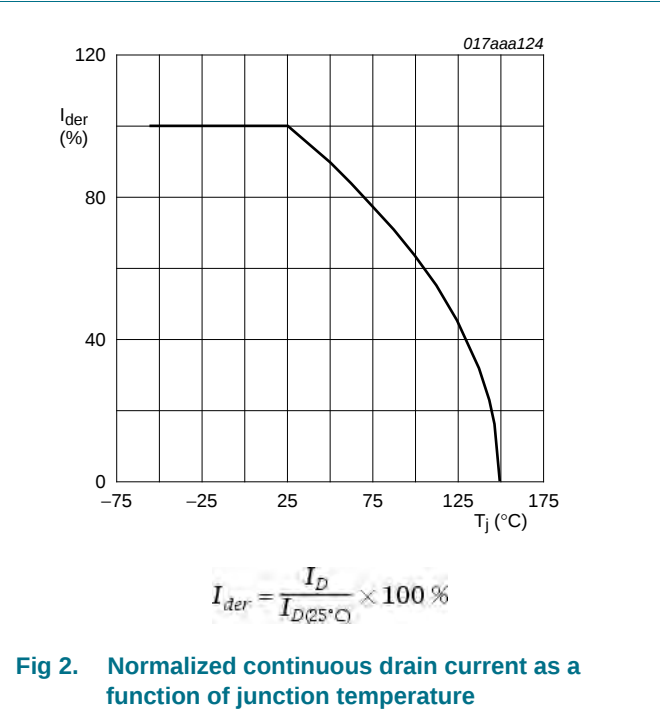
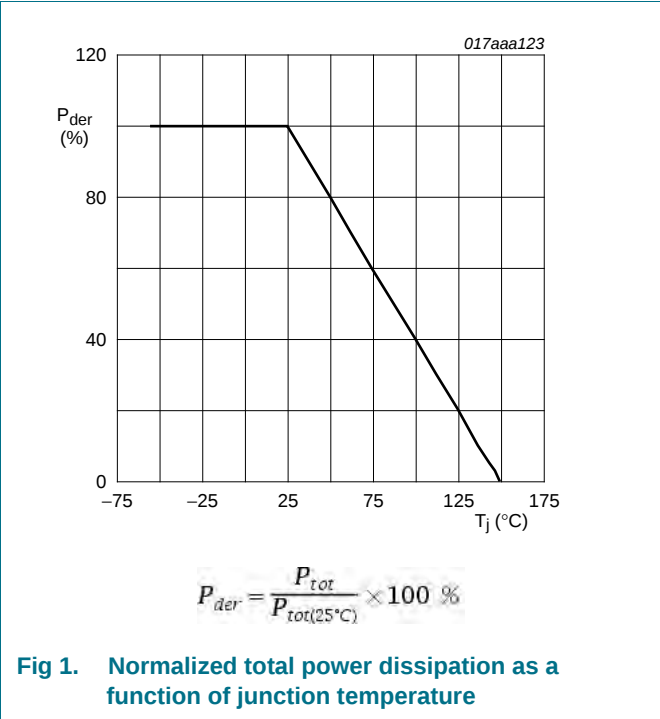
[1] % = placeholder for manufacturing site code

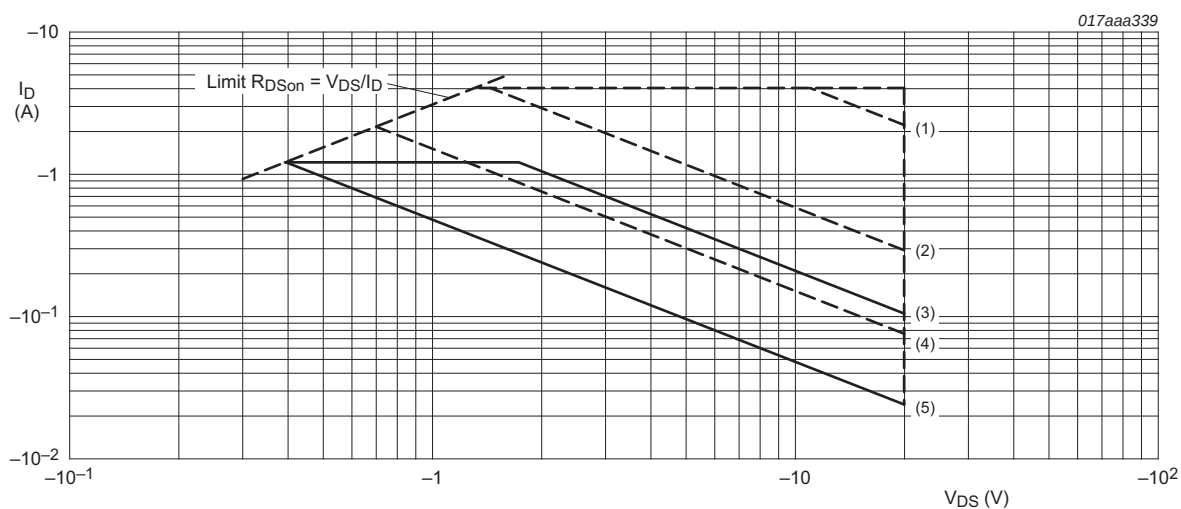
5. Limiting values

Table 5. Limiting values  
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol             | Parameter               | Conditions                                                     | Min | Max  | Unit   |
|--------------------|-------------------------|----------------------------------------------------------------|-----|------|--------|
| V <sub>DS</sub>    | drain-source voltage    | T <sub>j</sub> = 25 °C                                         | -   | -20  | V      |
| V <sub>GS</sub>    | gate-source voltage     |                                                                | -8  | 8    | V      |
| I <sub>D</sub>     | drain current           | V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> 25 °C               | [1] | -    | -1.2 A |
|                    |                         | V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 100 °C            | [1] | -    | -0.8 A |
| I <sub>DM</sub>    | peak drain current      | T <sub>amb</sub> = 25 °C; single pulse; t <sub>p</sub> ≤ 10 μs | -   | -4   | A      |
| P <sub>tot</sub>   | total power dissipation | T <sub>amb</sub> = 25 °C                                       | [2] | -    | 335 mW |
|                    |                         |                                                                | [1] | -    | 480 mW |
|                    |                         | T <sub>sp</sub> = 25 °C                                        | -   | 2170 | mW     |
| T <sub>j</sub>     | junction temperature    |                                                                | -55 | 150  | °C     |
| T <sub>amb</sub>   | ambient temperature     |                                                                | -55 | 150  | °C     |
| T <sub>stg</sub>   | storage temperature     |                                                                | -65 | 150  | °C     |
| Source-drain diode |                         |                                                                |     |      |        |
| I <sub>S</sub>     | source current          | T <sub>amb</sub> = 25 °C                                       | [1] | -    | -0.5 A |

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.  
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.





$I_{DM}$  = single pulse

(1)  $t_p = 1$  ms

(2)  $t_p = 10$  ms

(3) DC;  $T_{sp} = 25$  °C

(4)  $t_p = 100$  ms

(5) DC;  $T_{amb} = 25$  °C; drain mounting pad  $6$  cm<sup>2</sup>

**Fig 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage**

6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol         | Parameter                                        | Conditions  | Min | Typ | Max | Unit    |
|----------------|--------------------------------------------------|-------------|-----|-----|-----|---------|
| $R_{th(j-a)}$  | thermal resistance from junction to ambient      | in free air | [1] | -   | 325 | 374 K/W |
|                |                                                  |             | [2] | -   | 227 | 260 K/W |
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point |             | -   | 50  | 60  | K/W     |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.  
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

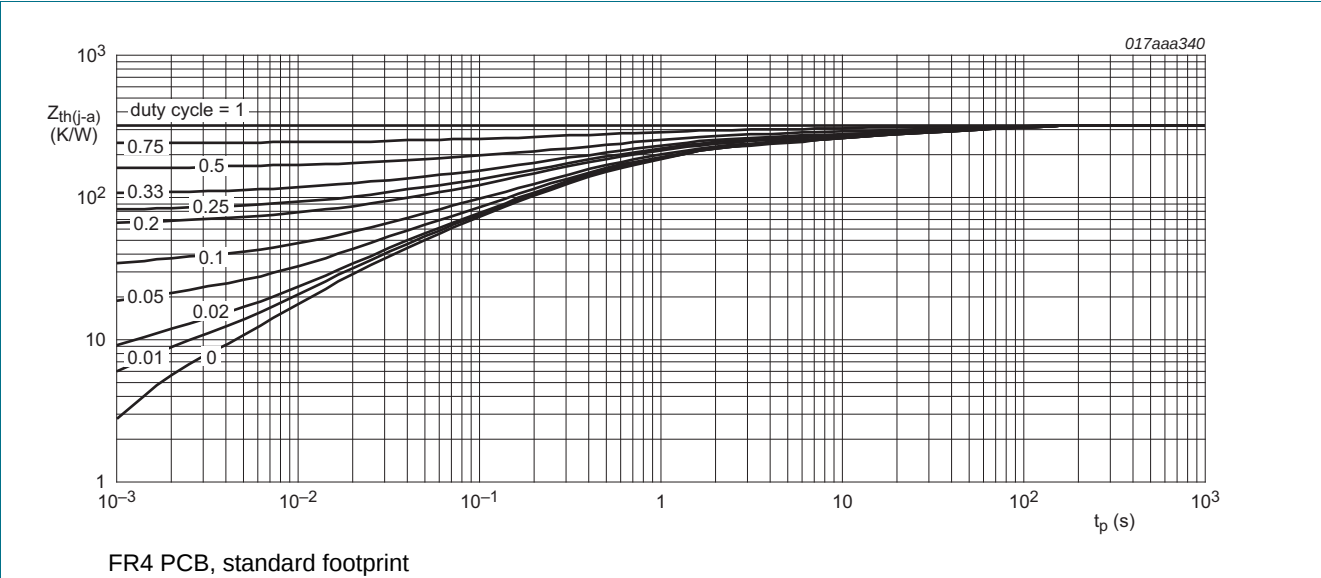


Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

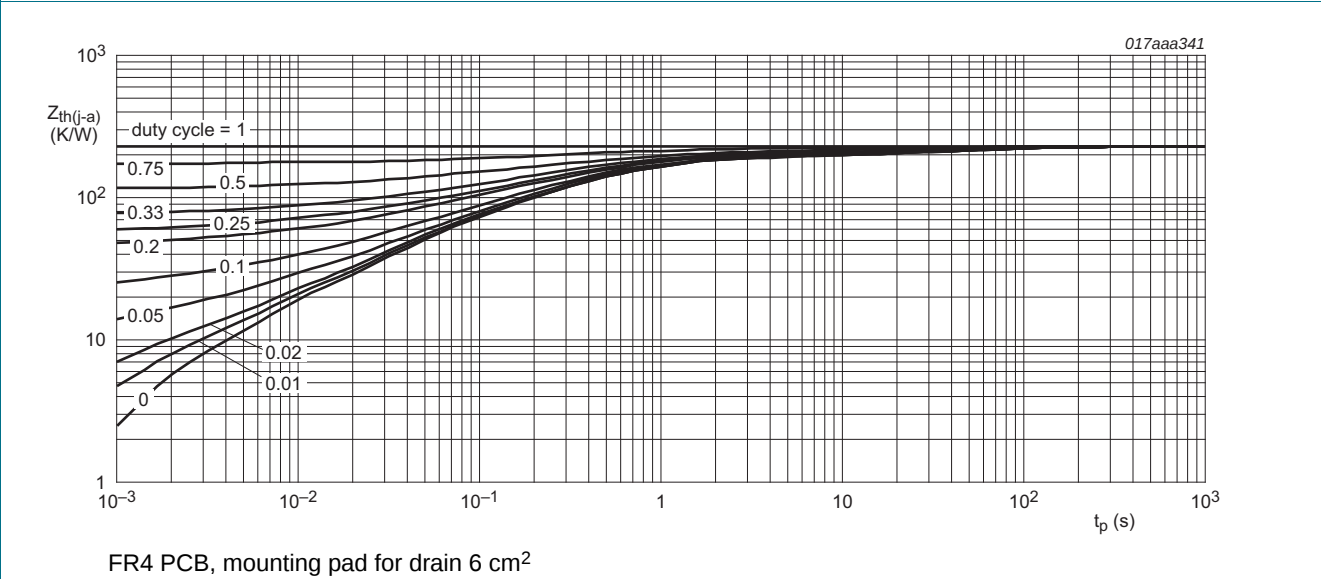
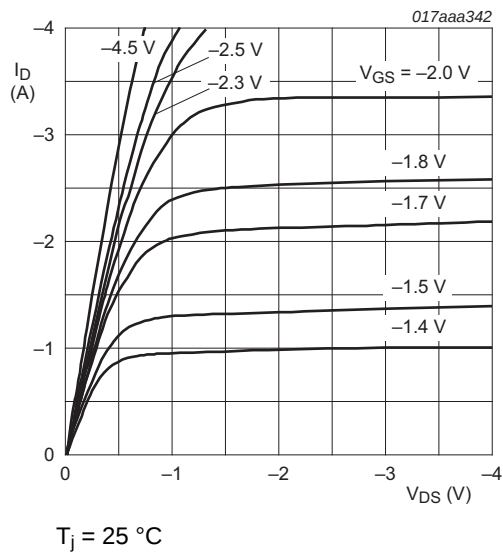


Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

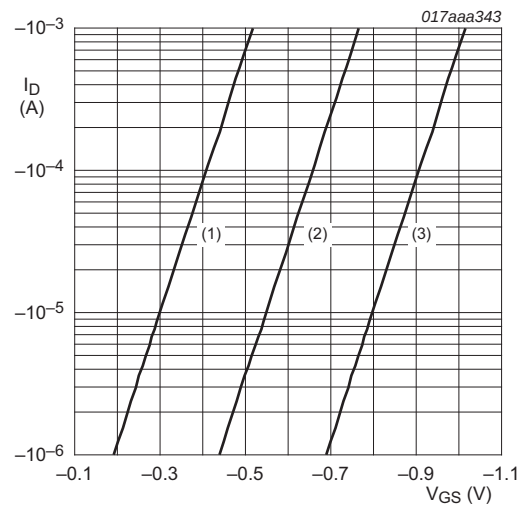
## 7. Characteristics

**Table 7. Characteristics**

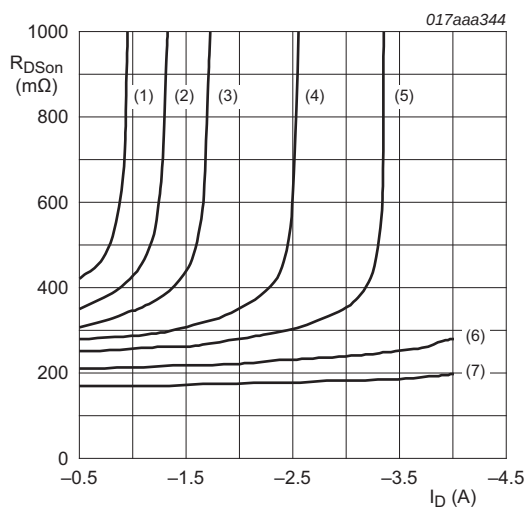
| Symbol                         | Parameter                        | Conditions                                                                                                                          | Min   | Typ  | Max   | Unit          |
|--------------------------------|----------------------------------|-------------------------------------------------------------------------------------------------------------------------------------|-------|------|-------|---------------|
| <b>Static characteristics</b>  |                                  |                                                                                                                                     |       |      |       |               |
| $V_{(BR)DSS}$                  | drain-source breakdown voltage   | $I_D = -250\ \mu\text{A}$ ; $V_{GS} = 0\ \text{V}$ ; $T_j = 25\ ^\circ\text{C}$                                                     | -20   | -    | -     | V             |
| $V_{GSth}$                     | gate-source threshold voltage    | $I_D = -250\ \mu\text{A}$ ; $V_{DS} = V_{GS}$ ; $T_j = 25\ ^\circ\text{C}$                                                          | -0.45 | -0.7 | -0.95 | V             |
| $I_{DSS}$                      | drain leakage current            | $V_{DS} = -20\ \text{V}$ ; $V_{GS} = 0\ \text{V}$ ; $T_j = 25\ ^\circ\text{C}$                                                      | -     | -    | -1    | $\mu\text{A}$ |
|                                |                                  | $V_{DS} = -20\ \text{V}$ ; $V_{GS} = 0\ \text{V}$ ; $T_j = 150\ ^\circ\text{C}$                                                     | -     | -    | -10   | $\mu\text{A}$ |
| $I_{GSS}$                      | gate leakage current             | $V_{GS} = -8\ \text{V}$ ; $V_{DS} = 0\ \text{V}$ ; $T_j = 25\ ^\circ\text{C}$                                                       | -     | -    | -100  | nA            |
|                                |                                  | $V_{GS} = 8\ \text{V}$ ; $V_{DS} = 0\ \text{V}$ ; $T_j = 25\ ^\circ\text{C}$                                                        | -     | -    | -100  | nA            |
| $R_{DSon}$                     | drain-source on-state resistance | $V_{GS} = -4.5\ \text{V}$ ; $I_D = -1.2\ \text{A}$ ; $T_j = 25\ ^\circ\text{C}$                                                     | -     | 170  | 210   | m $\Omega$    |
|                                |                                  | $V_{GS} = -4.5\ \text{V}$ ; $I_D = -1.2\ \text{A}$ ; $T_j = 150\ ^\circ\text{C}$                                                    | -     | 265  | 328   | m $\Omega$    |
|                                |                                  | $V_{GS} = -2.5\ \text{V}$ ; $I_D = -1.1\ \text{A}$ ; $T_j = 25\ ^\circ\text{C}$                                                     | -     | 210  | 270   | m $\Omega$    |
|                                |                                  | $V_{GS} = -1.8\ \text{V}$ ; $I_D = -0.5\ \text{A}$ ; $T_j = 25\ ^\circ\text{C}$                                                     | -     | 280  | 380   | m $\Omega$    |
| $g_{fs}$                       | forward transconductance         | $V_{DS} = -5\ \text{V}$ ; $I_D = -1.2\ \text{A}$ ; $T_j = 25\ ^\circ\text{C}$                                                       | -     | 3.7  | -     | S             |
| <b>Dynamic characteristics</b> |                                  |                                                                                                                                     |       |      |       |               |
| $Q_{G(tot)}$                   | total gate charge                | $V_{DS} = -10\ \text{V}$ ; $I_D = -1\ \text{A}$ ; $V_{GS} = -4.5\ \text{V}$ ; $T_j = 25\ ^\circ\text{C}$                            | -     | 3.3  | 4     | nC            |
| $Q_{GS}$                       | gate-source charge               |                                                                                                                                     | -     | 1    | -     | nC            |
| $Q_{GD}$                       | gate-drain charge                |                                                                                                                                     | -     | 0.5  | -     | nC            |
| $C_{iss}$                      | input capacitance                | $V_{DS} = -10\ \text{V}$ ; $f = 1\ \text{MHz}$ ; $V_{GS} = 0\ \text{V}$ ; $T_j = 25\ ^\circ\text{C}$                                | -     | 365  | -     | pF            |
| $C_{oss}$                      | output capacitance               |                                                                                                                                     | -     | 42   | -     | pF            |
| $C_{rss}$                      | reverse transfer capacitance     |                                                                                                                                     | -     | 30   | -     | pF            |
| $t_{d(on)}$                    | turn-on delay time               | $V_{DS} = -10\ \text{V}$ ; $V_{GS} = -4.5\ \text{V}$ ; $R_{G(ext)} = 6\ \Omega$ ; $T_j = 25\ ^\circ\text{C}$ ; $I_D = -1\ \text{A}$ | -     | 7    | -     | ns            |
| $t_r$                          | rise time                        |                                                                                                                                     | -     | 26   | -     | ns            |
| $t_{d(off)}$                   | turn-off delay time              |                                                                                                                                     | -     | 35   | -     | ns            |
| $t_f$                          | fall time                        |                                                                                                                                     | -     | 17   | -     | ns            |
| <b>Source-drain diode</b>      |                                  |                                                                                                                                     |       |      |       |               |
| $V_{SD}$                       | source-drain voltage             | $I_S = -0.5\ \text{A}$ ; $V_{GS} = 0\ \text{V}$ ; $T_j = 25\ ^\circ\text{C}$                                                        | -     | -0.7 | -1.2  | V             |



**Fig 6. Output characteristics: drain current as a function of drain-source voltage; typical values**

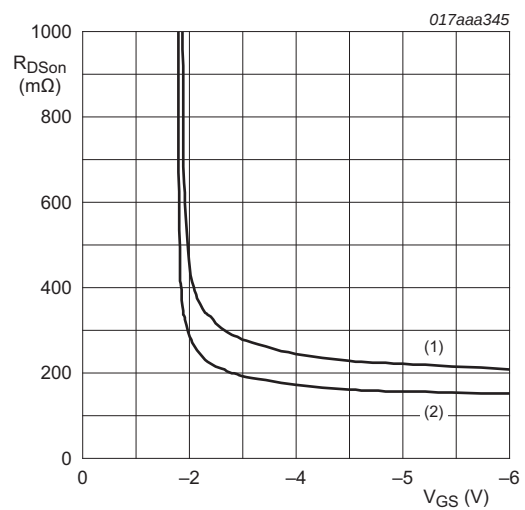


**Fig 7. Sub-threshold drain current as a function of gate-source voltage**  
 $T_j = 25\text{ °C}; V_{DS} = -5\text{ V}$   
 (1) minimum values  
 (2) typical values  
 (3) maximum values



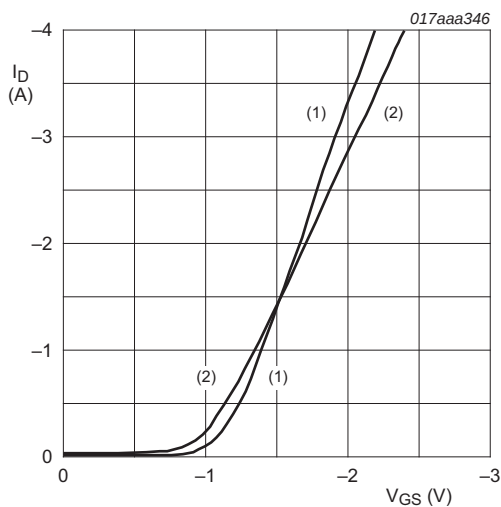
$T_j = 25\text{ °C}$   
 (1)  $V_{GS} = -1.4\text{ V}$   
 (2)  $V_{GS} = -1.5\text{ V}$   
 (3)  $V_{GS} = -1.6\text{ V}$   
 (4)  $V_{GS} = -1.8\text{ V}$   
 (5)  $V_{GS} = -2.0\text{ V}$   
 (6)  $V_{GS} = -2.5\text{ V}$   
 (7)  $V_{GS} = -4.5\text{ V}$

**Fig 8. Drain-source on-state resistance as a function of drain current; typical values**



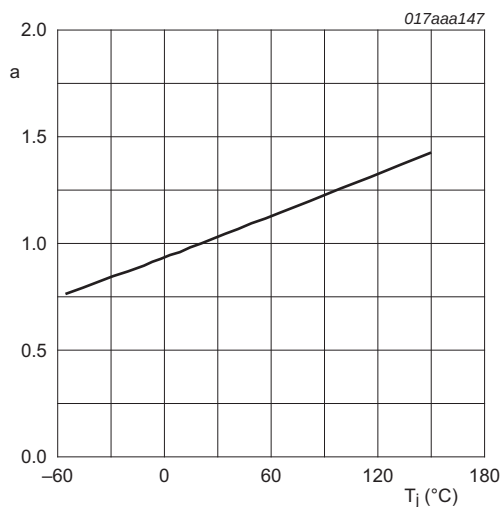
$I_D = -2.5\text{ A}$   
 (1)  $T_j = 150\text{ °C}$   
 (2)  $T_j = 25\text{ °C}$

**Fig 9. Drain-source on-state resistance as a function of gate-source voltage; typical values**



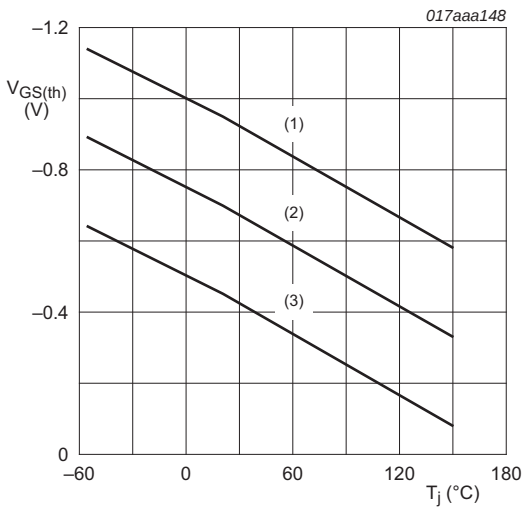
$V_{DS} > I_D \times R_{DSon}$   
(1)  $T_j = 25\text{ °C}$   
(2)  $T_j = 150\text{ °C}$

Fig 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values



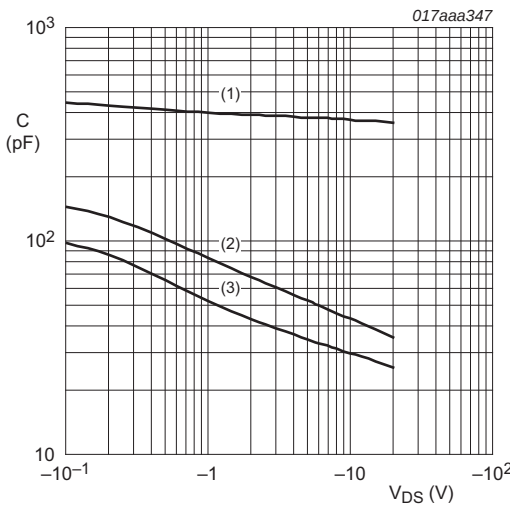
$$a = \frac{R_{DSon}}{R_{DSon}(25\text{ °C})}$$

Fig 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values



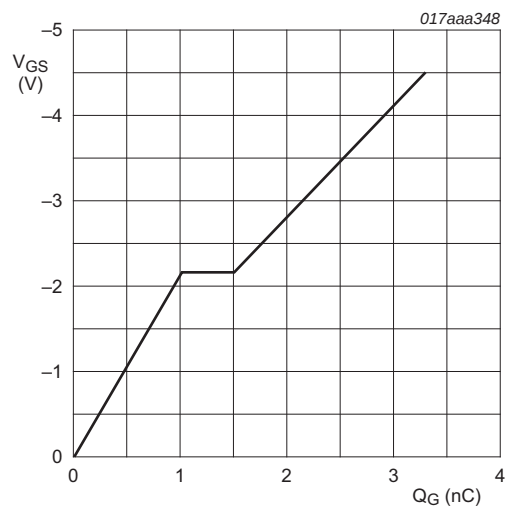
$I_D = -0.25\text{ mA}$ ;  $V_{DS} = V_{GS}$   
(1) maximum values  
(2) typical values  
(3) minimum values

Fig 12. Gate-source threshold voltage as a function of junction temperature



$f = 1\text{ MHz}$ ;  $V_{GS} = 0\text{ V}$   
(1)  $C_{iss}$   
(2)  $C_{oss}$   
(3)  $C_{rss}$

Fig 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



$I_D = -1.0$  A;  $V_{DS} = -10$  V;  $T_{amb} = 25$  °C

Fig 14. Gate-source voltage as a function of gate charge; typical values

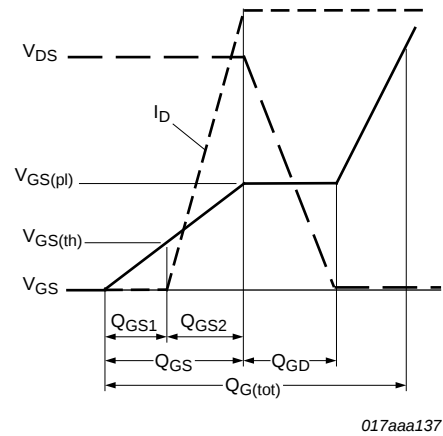
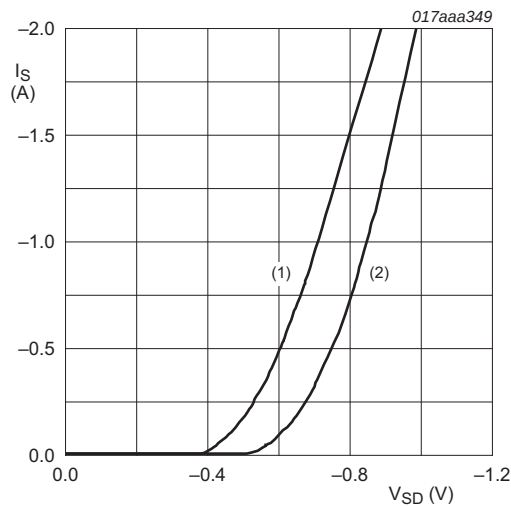


Fig 15. Gate charge waveform definitions



$V_{GS} = 0$  V  
(1)  $T_j = 150$  °C  
(2)  $T_j = 25$  °C

Fig 16. Source current as a function of source-drain voltage; typical values

## 8. Test information

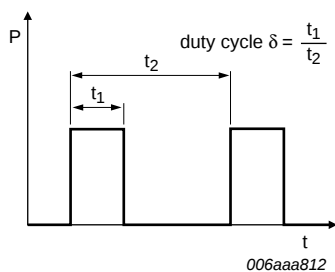


Fig 17. Duty cycle definition

9. Package outline

Plastic surface-mounted package; 3 leads

SOT23

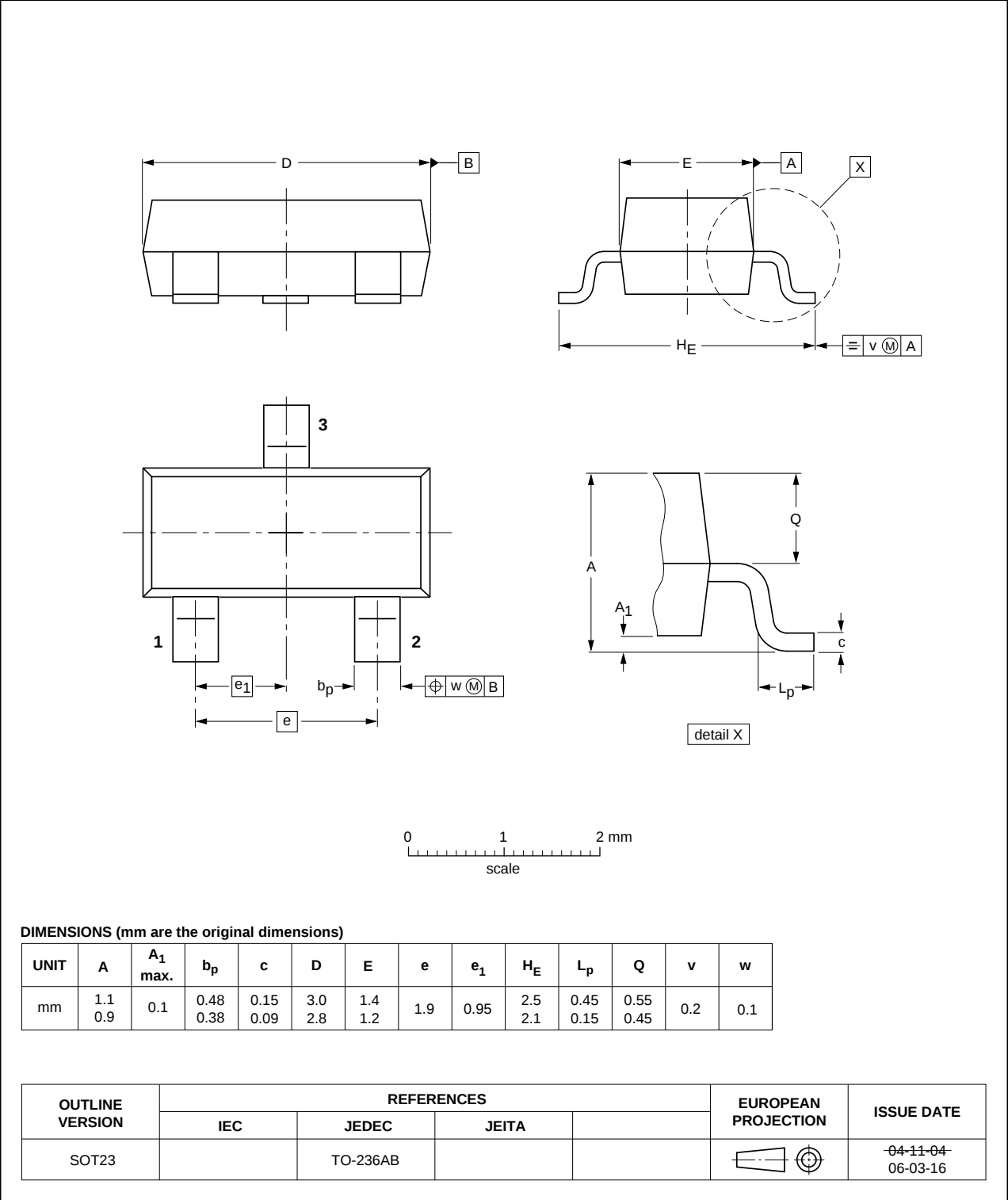


Fig 18. Package outline SOT23 (TO-236AB)

10. Soldering

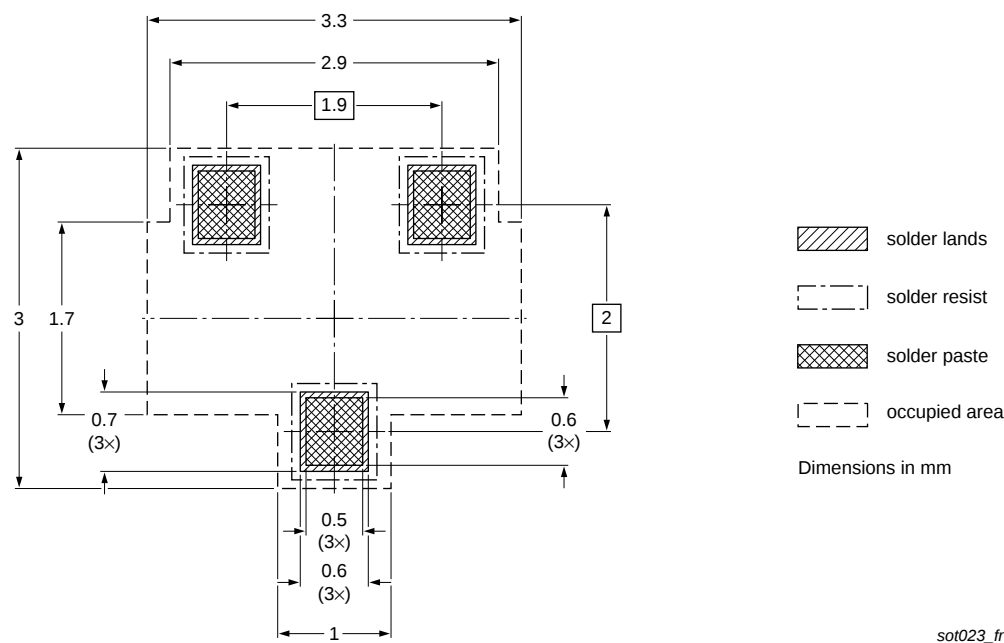


Fig 19. Reflow soldering footprint for SOT23 (TO-236AB)

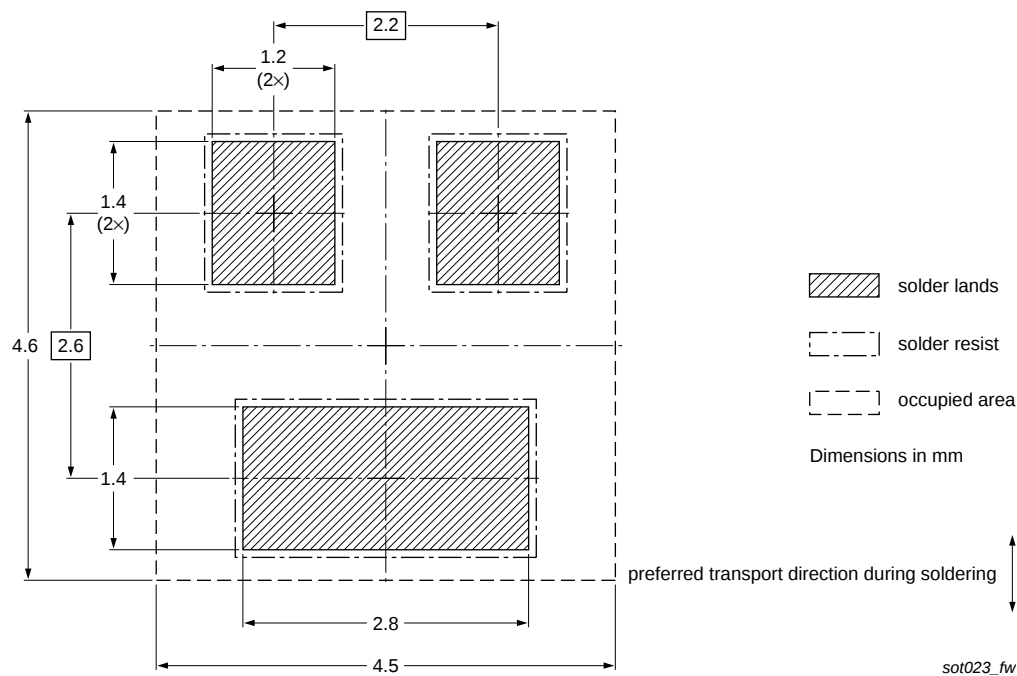


Fig 20. Wave soldering footprint for SOT23 (TO-236AB)

## 11. Revision history

Table 8. Revision history

| Document ID    | Release date                                                                                                                      | Data sheet status  | Change notice | Supersedes   |
|----------------|-----------------------------------------------------------------------------------------------------------------------------------|--------------------|---------------|--------------|
| PMV160UP v.2   | 20111206                                                                                                                          | Product data sheet | -             | PMV160UP v.1 |
| Modifications: | <ul style="list-style-type: none"><li><a href="#">7 "Characteristics"</a>: <math>V_{GSth}</math> condition is corrected</li></ul> |                    |               |              |
| PMV160UP v.1   | 20110907                                                                                                                          | Product data sheet | -             | -            |

## 12. Legal information

### 12.1 Data sheet status

| Document status <sup>[1] [2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|------------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet       | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet     | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet         | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nexperia.com>.

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